Proposed Scheme and Syllabi of M.Sc. Physics 2nd Year for A.Y. 2024-25

Semester-III:

| S. No. | Course Code | Course Title | L | Т | Р | Credits |
|--------|--|------------------------|--------------|-------|----|---------|
| 1. | PHPC515 | Advanced Electronics | 3 0 0 | | 0 | 3 |
| 2. | PHPC517Condensed Matter Physics300 | | 0 | 3 | | |
| 3. | PHPE5## | Programme Elective - I | 3 | 0 | 0 | 3 |
| 4. | PHPE5## | Programme Elective -II | 3 | 3 0 0 | | 3 |
| 5. | PHOE### | Open Elective - I | 3 | 0 0 | | 3 |
| 6. | PHPC519 | Advanced Physics Lab | 0 | 0 6 | | 3 |
| 7. | PHPC521 | Seminar | 0 | 0 | 1 | 1 |
| 8. | 8.PHPC523Preparatory Research Project004 | | 4 | 2 | | |
| | | | Total Credit | | 21 | |

Semester-IV:

| S. No. | Course Code | Course Title | L | Т | Р | Credits |
|--------|--------------------|---------------------------------|--------------|-----|----|---------|
| 1. | PHPE5## | Programme Elective – III | 3 | 0 | 0 | 3 |
| 2. | PHPE5## | Programme Elective - IV* | 3 | 0 | 0 | 3 |
| 3. | PHOE### | Open Electives-II* | 3 | 0 0 | | 3 |
| 4. | PHPC522 | Research Project (Dissertation) | 0 0 20 | | 10 | |
| | | | Total Credit | | 19 | |

| Course Code PHPC 515 | Advanced Electronics | Credits 3-0-0: 3 |
|--|--|--|
| | tional Objectives : | 5-0-0.5 |
| | niliarize the students about advanced electronic devices and their application | ົງກຽ |
| | velop understanding of design Digital circuits and interfacing simple system | |
| | controllers. | ins using |
| | velop understanding of Communication systems. | |
| UNIT-1 | | 9 L |
| | r Devices: Drift and diffusion of carriers, Generation and recombination of | |
| | nductors. P-N junction, diode equation, barrier width and Capacitance of PN | U , |
| | e, FET as switch and amplifier, Optoelectronic Devices: LEDs, Diodes La | |
| and Solar Cells | | , |
| UNIT-2 | | 9 L |
| Advanced Ele | ctronic Devices: Metal Oxide Field Effect Transistors (MOSFET), Short C | hannel Effects in |
| MOSFET, Fin | Field-Effect Transistors (FinFETs), Ferroelectric field effect devices and 21 | D nanosheet |
| devices; Emerg | ing Memory devices: DRAM, ReRAM, FeRAM and Phase Change memory | ry (PCM) and |
| universal mem | bry devices. | |
| UNIT-3 | | 10 L |
| applications; lo Sensors: Temp Design of com system, digital Design of Seq CMOS operation | ns: Phase-lock loop and its applications frequency multiplication; Analog and antilog amplifiers; Instrumentation amplifiers; erature, Magnetic field, Displacement, Light intensity and Force sensors binational circuits: Programming logic devices and gate arrays, 7- segme gain control, analog multiplexers, PC based measurement system; cential circuits: Different types of A/D and D/A conversion techniques, bon and specifications. | nt and LCD display |
| UNIT-4 | | 9 L |
| ideas about te amplitude, puls Pulse modulati modulation (PC | on Systems: Concepts of communication systems, role of electromagnetic syminology of communication systems, Need for modulation, amplitud as position, pulse code modulation, Information in communication system on, Pulse width modulation (PWM), Pulse position Modulation (PPM), Pri CM); Introduction to digital communication. | e, frequency, pulse n, Coding, Types of |
| Reference Boo | | |
| | Physics of semiconductor devices, Wiley, 2021. | |
| | & Grable, Microelectronics, McGraw Hill, 2017. | |
| | Kurinec, Nanoscale Semiconductor Memories. | |
| | Id Leach , Digital Principles & Applications, II edition, McGraw Hill, 2017. | |
| | ecommunications, CBS Publisher, 2019. | |
| 6. J. D. Ryde | r, Electronic fundamental and applications, Prentice Hall India, 1975. | |
| Course Outco | nes: Students will be able to: | |

| Course | Course Outcomes: Students will be able to: | | | | |
|--------|---|--|--|--|--|
| CO1 | Illustrate the basic concepts and applications of different Analog systems. | | | | |
| CO2 | Design different digital electronic circuits such as 7 segment and LCD display systems. | | | | |
| CO3 | Illustrate the basic concepts of Communication systems. | | | | |

| Course Code PHPC 517 | | Condensed Matter Physics | Credits 3-0-0: 3 | |
|-------------------------|---|--------------------------|---------------------|--|
| Course | Educati | onal Objectives : | | |
| COE1 | To familiarize the students about the fundamentals of Semiconductor Physics and its applications. | | | |
| COE2 | To develop understanding of dielectric behavior of materials in electro- magnetic fields. | | | |
| COE3 | COE3 To develop understanding of magnetic and superconducting behavior of various condensed | | sed matter | |
| | systems | h. | | |
| UNIT | UNIT-1 9 | | | |

Semiconductors: Semiconductor materials, Elemental and compound semiconductors, Energy bands, Direct and indirect Band gap semiconductors, Density of states, effective mass, donors and acceptors, Degenerate and Non-degenerate Semiconductors, Equilibrium and extrinsic carrier concentration, carrier transport, Drift and Diffusion current, mobility, Einstein relation, Excess carrier generation and recombination.

UNIT-2

Dielectrics: Polarization, Bound Charges, Electric displacement, susceptibility, dielectric coefficient, and permittivity, Dielectrics in AC fields, Clausius- Mossotti equation, polarizability- classical theory of electronic polarizability, dipolar polarizability, Effect of temperature and frequency on dielectric constant and dielectrics loss factor, Piezo-, Pyro- and ferroelectric solids, ferroelectric domains, ferroelectricity, anti-ferroelectricity and ferrielectricity, Applications of dielectrics.

UNIT-3

Magnetism: Classification of magnetic materials, origin of permanent magnetic moments, Langevin's classical theory of diamagnetism, Magnetic susceptibility, Quantum theory of paramagnetism, ferromagnetism, Weiss theory, ferromagnetic domains, Ferromagnetic order, Hysteresis, anti-ferromagnetism, Curie temperature and Neel temperature, ferrimagnetism and anti-ferrimagnetism, Susceptibility measurements- Guoy Balance; Quincke's method.

UNIT-4

Superconductors: Zero resistivity, Critical temperature, Meissner effect, London equation, Type I and II superconductors, thermodynamics, superconducting band gap, Cooper pairs, flux quantization, BCS theory, Josephson Effect, SQUIDS, High temperature superconductors, Applications of superconductivity.

Reference Books:

- 1. Kittel C., Introduction to Solid State Physics, Wiley, 2007.
- 2. Ben G. Streetman, Prentice-Hall of India, Solid State Electronic Devices, 2012
- 3. Jaspreet Singh, John Wiley, Semiconductor Devices-Basic Principles, publication, 2008
- M A Wahab, Solid State Physics-Structure and Properties of Materials, Narosa, 2005.

| Course | Course Outcomes: Students will be able to: | | | | |
|--------|---|--|--|--|--|
| CO1 | Understand the Semiconductor Physics and strategies for realizing its various applications. | | | | |
| CO2 | Disseminate their understanding on behaviour of dielectric materials in electro- magnetic fields. | | | | |
| CO3 | Understand the concept of superconductivity and magnetism. | | | | |

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Programme Elective – I (Semester-III):

| S. No. | Course Code | Course Title |
|--------|--------------------|---|
| 1. | PHPE 551 | Quantum Field Theory |
| 2. | PHPE 553 | Lasers and Spectroscopy |
| 3. | PHPE 555 | Functional Materials and Characterization |

Programme Elective – II (Semester-III):

| S. No. | Course Code | Course Title | | |
|--------|--------------------|---|--|--|
| 1. | PHPE 557 | Radiation Physics and Nuclear Fragmentation | | |
| 2. | PHPE 559 | Nonlinear Spectroscopy | | |
| 3. | PHPE 561 | Materials Science | | |

Programme Elective – III (Semester-IV):

| S. No. | Course Code | Course Title |
|--------|--------------------|------------------------------------|
| 1. | PHPE 552 | High Energy Physics |
| 2. | PHPE 554 | Photonics |
| 3. | PHPE 556 | Thin Film Physics and Applications |

Programme Elective – IV (Semester-IV):

| S. No. | Course Code | Course Title |
|--------|--------------------|------------------------------------|
| 1. | PHPE 558 | Nuclear Technology |
| 2. | PHPE 560 | Physics of Optoelectronics Devices |
| 3. | PHPE ### | NPTEL/SWAYAM/edX |

Programme Elective NPTEL/SWAYAM/edX Courses:

| S.No. | Course Code | Course Title |
|-------|--------------------|---|
| 1. | PHPE ### | Accelerator Physics |
| 2. | PHPE ### | Neutron Scattering for Condensed Matter |
| | | Studies |
| 3. | PHPE ### | Scientific Computing Using Python |
| 4. | PHPE ### | Numerical Methods and Simulation |
| | | Techniques for Scientists and Engineers |
| 5. | PHPE ### | Computational Physics |
| 6. | PHPE ### | A Brief Course On Superconductivity |
| 7. | PHPE ### | Physics Of Linear And |
| | | Nonlinear Optical Waveguides |
| 8. | PHPE ### | Solar Photovoltaics Fundamentals, |
| | | Technology and applications |

| Course PHPF | | Quantum Field Theory | Credits 3-0-0: 3 |
|--|--|--|--|
| Course | Educati | onal Objectives : | |
| COE1 | | liarize the students about interaction among fundamental entities of the universe | |
| COE2 | To deve | lop understanding of perturbation theory and Feynman Rules to apply in high e | nergy |
| | | ng measurements. | |
| COE3 | To deve | lop understanding of bound state structure. | |
| UNIT-1 | 1 | | 10 L |
| Field St Electric The Kle | rength T and Mag in-Gord | ctrodynamics: Maxwell's Equations in Relativistic Form, four-current, four- censor, Maxwell's inhomogeneous and Homogeneous equations, Transforma gnetic Fields. Ion Field: Elements of Classical Field Theory, The Klein-Gordon field as Harmo on field in Space-time, Classical Propagator and particle creation by a classical s | nic Oscillator, |
| UNIT-2 | | | 8 L |
| the Dira Charge O UNIT- Quantu function | c Field, ' Conjugat 3 m Elect s. Wick' | Dirac Equations and Spin sum rule, Dirac Matrices and Dirac Field Bilinears, Quantum Electrod The Dirac Propagator, Discrete symmetries of the Dirac Theory, Parity, Time Re- tion. rodynamics and Feynman diagrams: Perturbation Theory and expansion of s Theorem, Feynman Diagrams, Cross-sections and the S-matrix calculation f than Rules for Fermions, Yukawa Theory, Feynman Rules for Quantum Electrod | eversal, 8 L of Correlation rom Feynman |
| Coulom | b Potenti | al. | - |
| UNIT- | 4 | | 10 L |
| Cross-Se | ections, | Elementary process: Electron Muon High Energy Scattering, Trace technology Helicity Structure, Crossing Symmetry, Mandelstam Variables, Compton Scatt, Klein-Nishina Formula, Pair annihilation into photons. | · • |
| Referen | | | |
| Son 2. D. J. 3. Rich 4. W. G 5. C. Ce WII | s, 1993. Griffiths ard P. Fe reiner, J ohen-Tau LEY VCH | A. Martin, Quarks and Leptons: An Introductory Course in Modern Particle Physics, a. Introduction to elementary Particles, John Wiley & Sons, 2006. b. Synman, The strange Theory of Light and Matter, Prinston University Press, 1983. c. Reinhart, Quantum Electrodynamics, Springer, 2003. a. Introduction to quantum electrodynamics. Introduction to quantum electrodynamical definition of the strange of the strange of the strange. b. Verlag GmbH & Co. KGaA, 1997. c. Pal, A first Book of Quantum Field Theory, Narosa Publication, 2007. | |

| Course | Course Outcomes: Students will be able to: | | |
|--------|--|--|--|
| CO1 | Estimate the interaction strength among fundamental constituent of the universe. | | |
| CO2 | Apply Feynman rules technique to the high energy scattering process measured in experiments like | | |
| | LHC, COMPASS, HERA, LEP etc. | | |
| CO3 | Cultivate critical thinking on symmetries and conservation laws involved in cutting edge research. | | |

| Course Code PHPE 553 | | Lasers and Spectroscopy | Credits 3-0-0: 3 | |
|--|---|--|---|--|
| | | onal Objectives : | 5-0-0.5 | |
| COE1 | | elop the understanding of Laser technology and Laser based devices. | | |
| COE2 | | n Vibrational spectroscopy and related technologies. | | |
| COE3 | | erstand various laser based detection techniques and instrumentation. | | |
| UNIT- | | | 9 L | |
| level sys | tem, Fo n, Laser | Itals: Einstein coefficients, Population inversion, Line shape function, ur level system, Optical resonators, Laser cavity design; cavity mo- properties, Pulse amplification techniques (Q-Switch, Mode-locking tion of laser output. | des, laser spiking, gain | |
| UNIT- | 2 | | 9 L | |
| | | Solid State Lasers: Concept, design and applications, Nd:YAG Laser s: He:Ne, CO ₂ laser, Excimer laser; Dye laser; Fiber laser. | , Semiconductor lasers, | |
| | UNIT-3 9L | | | |
| and math Overtone | hematicate and control oility elli | aman Spectroscopy: Vibrational Degree of freedom, Normal coordin al formulations, Degenerate vibrations, Infrared spectra: Active a ombination vibrations, Vibrational Raman Spectra: concept, Math psoid, Overtone and combination vibrations, Polarization of Rayleigh | nd inactive vibrations, ematical Formulations, | |
| and time | Spectroscopic techniques: Spectroscopic processes, Absorption and fluorescence spectroscopy, Steady-state and time-resolved emission spectroscopy, Raman Spectroscopy, Stand-off Laser Spectroscopy, Cavity ring-down laser absorption spectroscopy, Laser Induced Breakdown Spectroscopy, Photoacoustic Spectroscopy. | | | |
| Reference | | | | |
| 2. John 3. John 2005 4. Colin | William T. Silfvast, Laser Fundamentals, Cambridge University Press, 2003. John F. Ready, Industrial Applications of Lasers, Acedamic Press, 1997. John Ion, Laser Processing of Engineering Materials: Principles, Procedure and Industrial Applications, Elsevier, 2005. Colin N. Banwell & Elaine M. McCash, Fundamentals of molecular spectroscopy, McGraw Hill, 2017. G. Aruldhas, Molecular structure and Spectroscopy, Prentice - Hall of India, 2007. | | | |

| Course Outcomes: Students will be able to: | | | |
|--|---|--|--|
| CO1 | Learn the concept of lasers, its instrumentation and will be able to design and develop lab scale lasers. | | |
| CO2 | Use vibrational spectroscopy for various applications related to molecular analysis. | | |
| CO3 | Develop new spectroscopic technique and perform experiments. | | |

| PHPE | Code 555 | Functional Materials and Characterization | Credits 3-0-0: 3 | |
|---|--|--|---|--|
| Course Educational Objectives : | | | | |
| COE1 | - | To provide an overview of functional materials' design, composition, processing processes, structure, and physical properties. | | |
| COE2 | | To familiarize the students with different techniques associated with the fabrication and physical property testing of functional materials. | | |
| COE3 | | To impart knowledge and develop the understanding of applications of a range of advanced functional materials. | | |
| UNIT-1 | 1 | | 9 L | |
| Functional Materials And Nanotechnology: Introduction to functional materials (magnetism, ferroelectricity, piezoelectricity, semiconductors, polymers, and storage) and nanotechnology: definitions and background, a brief history, scales and sizes, size effects, elegant examples from nature and materials science, nanotechnology, environmental and health impact. | | | | |
| UNIT-2 | | | 9 L | |
| Functional Materials Synthesis: Top-down and Bottom-up approaches for synthesis of functional materials; Ball milling, Electron Beam Lithography, Atomic Layer Deposition, Pulse Laser Deposition, Spray pyrolysis, Chemical Vapor Deposition (CVD), Sol-gels, Hydrothermal methods, Microwave, Spin and Dip coating techniques. | | | | |
| UNIT | | | 9 L | |
| | | verials Characterization : XRD, Raman, UV-VIS-Spectroscopy, Microscopy (S sample magnetometer (VSM), PE-loop tracer, Electrochemical workstation. | | |
| <i>,</i> , | UNIT-4 9L | | | |
| UNIT-4 | | | SPM, TEM, 9 L | |
| UNIT-4 Function photovol | nal Ma taic cell | terials Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H_2 storage and waste water treatment | SPM, TEM, 9 L optics and | |
| UNIT-4 Function photovol Reference | nal Ma taic cell <mark>ce Book</mark> | terials Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H ₂ storage and waste water treatmeters: | SPM, TEM, 9 L optics and | |
| UNIT-4 Function photovol Reference 1. Prince | nal Ma taic cell ce Book ciple of N | terials Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H ₂ storage and waste water treatm s: Nanoscience & Nanotechnology: M.A. Shah and T. Ahmad , Narosa, 2010. | SPM, TEM, 9 L optics and | |
| UNIT-4 Function photovol Reference 1. Prince 2. Nance | nal Ma taic cell ce Book ciple of I oscale M | terials Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H ₂ storage and waste water treatments: s: Nanoscience & Nanotechnology: M.A. Shah and T. Ahmad , Narosa, 2010. ultifunctional Materials : S. M. Mukhopadhyay , Wiley, 2012. | SPM, TEM, 9 L optics and | |
| UNIT-4 Function photovol Reference 1. Princ 2. Nanc 3. Elen | nal Ma taic cell ce Book ciple of I oscale M nents of 2 | terials Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H₂ storage and waste water treatmes: Nanoscience & Nanotechnology: M.A. Shah and T. Ahmad, Narosa, 2010. ultifunctional Materials: S. M. Mukhopadhyay, Wiley, 2012. X-ray Diffraction, B. D. Cullity, 4th Edition, Addison Wiley, 1978. | SPM, TEM, 9 L optics and | |
| UNIT-4 Function photovol Reference 1. Prince 2. Nance 3. Elem 4. Phys | nal Ma taic cell ce Book ciple of M oscale M nents of Fu sics of Fu | terials Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H₂ storage and waste water treatmes: Nanoscience & Nanotechnology: M.A. Shah and T. Ahmad, Narosa, 2010. ultifunctional Materials: S. M. Mukhopadhyay, Wiley, 2012. X-ray Diffraction, B. D. Cullity, 4th Edition, Addison Wiley, 1978. unctional Materials, HasseFredriksson& Ulla Akerlind, Wiley, 2015. | SPM, TEM, 9 L optics and tent. | |
| UNIT-4 Function photovol Reference 1. Prince 2. Nance 3. Elen 4. Physics 5. Function | nal Ma taic cell ce Book ciple of M oscale M nents of M sics of Fu ctional M | Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H₂ storage and waste water treatmes: Nanoscience & Nanotechnology: M.A. Shah and T. Ahmad, Narosa, 2010. ultifunctional Materials: S. M. Mukhopadhyay, Wiley, 2012. X-ray Diffraction, B. D. Cullity, 4th Edition, Addison Wiley, 1978. unctional Materials, HasseFredriksson& Ulla Akerlind, Wiley, 2015. Iaterials; Electrical, Dielectric, Electromagnetic, Optical, and Magnetic Applications, I | SPM, TEM, 9 L optics and tent. | |
| UNIT-4 Function photovol Reference 1. Prince 2. Nance 3. Elen 4. Phys 5. Funce Chu | nal Ma taic cell ce Book ciple of P oscale M ments of P sics of Fu ctional M ng, Wor | terials Applications: Applications of functional materials in electronics, s, sensors, fuel cells, batteries, supercapacitors H₂ storage and waste water treatmes: Nanoscience & Nanotechnology: M.A. Shah and T. Ahmad, Narosa, 2010. ultifunctional Materials: S. M. Mukhopadhyay, Wiley, 2012. X-ray Diffraction, B. D. Cullity, 4th Edition, Addison Wiley, 1978. unctional Materials, HasseFredriksson& Ulla Akerlind, Wiley, 2015. | SPM, TEM, 9 L optics and nent. Deborah DL | |

| Course | Course Outcomes: Students will be able to: | | |
|--------|--|--|--|
| CO1 | Understand functional materials behaviour to the design of new materials with novel properties. | | |
| CO2 | Utilize lithographic methods to fabricate functional materials. | | |
| CO3 | Use relationships between composition, processing route, microstructure, properties and applications | | |
| | of advanced functional materials. | | |

| Course PHPE | | Radiation Physics and Nuclear Fragmentation | Credits 3-0-0: 3 | |
|---|---|--|---|--|
| Course | Educat | ional Objectives : | | |
| CEO1 | CEO1 To give understanding of different types of radiations and their interaction of with matter. | | | |
| CEO2 | To gain knowledge about design and working of gas filled and semiconductor radiation detectors. | | | |
| CEO3 | To dev | velop the understanding of Solid state nuclear track detectors working and their appli | cation for | |
| | measu | rement of environmental radioactivity. | | |
| UNIT-1 | | | 9 L | |
| Effective Biologic Health e and its a Radiatio shielding | e dose, al Effects: pplicati n prote g. Exter 2 | ects of Radiation: Types of Radiation, Radiation Doses- Exposure dose, Absor special parameter, Weighting factor, Tissue Factor, background levels, LET and ctiveness. Schostic effects, Delayed Effect. Recomdation doses. Induction of chromosomal a on in biological dosimetry of absorbed radiation. Cell killing and induction of mutati ction standards: Need for protection, ALARA principle. Radiation Shielding, Time nal and internal exposure. ICRP and AERB recommendations. | Radiation berrations ions. , distance, 9 L | |
| formatio restricted | n, etch 1 energ neter, Se | Radiation Detection Devices : Track etch generation mechanisms, conditions ing and counting of tracks, properties and applications of SSNTD, detection t y loss, Active measurement techniques for environmental radioactivity; beta/gamma cintillation Radon Monitor (SRM), Scintillation Thoron Monitor (STM). | hresholds, | |
| | | nentation: High energy heavy ions, heavy ions interactions in matter, Energy loss in | | |
| heavy pa total frag changing | articles, gmentat g cross | odd-even effect in fragmentation, fragmentation cross sections of heavy ions in vario ion, charge-changing nuclear reactions of relativistic ions during the passage of matter sections, partial-charge changing cross-section, fragmentation of ultra-relativistic he dissociation. | us targets, er, charge- | |
| UNIT-4 | ļ | | 10 L | |
| heavy io Special | n therap techniq | apy: Photon therapy, electron therapy, charge particle therapy, hadrontherapy, systery, Bragg's peak analysis. ues in radiation therapy: Total Body Irradiation, Total Skin Electron Therapy, St SRS); SRS Delivery Systems, Linac based, Gamma Knife, Robotic | | |
| Referen | ce Bool | ks: | | |
| Nucle Solid Walk | ear Inst State N ker, Spr | etection and Measurement, T. Lewellen, Wiley, 2008. rumentation: W. J. Price, Johnes and Bartlett, 2012. Nuclear Track Detectors-Principal and Applications: R. L. Fleischer , P. B. Price & F inger, 1948. for nuclear and particle physics experiments: W. R. Leo, Springer, 1948. | к. М. | |
| Course | Outcor | nes: Students will be able to: | | |
| | | tand different types of radiations and their interaction of with matter. | | |
| CO2 | | tand design and working of gas filled and semiconductor radiation detectors with ass | sociated | |
| CO3 | Unders | tand solid state nuclear track detectors and their application for measurement of measurement and innental radioactivity. | | |

| Course Code PHPE 559 | | Nonlinear Spectroscopy | Credits 3-0-0: 3 | | |
|-------------------------|--|--|------------------|--|--|
| | | ional Objectives : | | | |
| CEO1 | | elop the understanding of nonlinear spectroscopy and various processes therein. | | | |
| CEO2 | To lear | n various nonlinear experimental methods. | | | |
| CEO3 | To und | erstand multiphoton absorption process and instrumentation | | | |
| UNIT-1 | 1 | | 9 L | | |
| Suscepti matchin | Fundamental : Wave Propagation in Nonlinear Medium, Nonlinear Polarization Density and Nonlinear Susceptibility, nonlinear optical coefficient, Saturable absorber, Phase Matching conditions, types of phase matching. | | | | |
| UNIT-2 | 2 | | 9L | | |
| generati | on, Para | Nonlinear process: Second Harmonic Generation (SHG), Sum and differen imetric oscillation, Optical parametric oscillator, Singly and Doubly resona G in KDP and LiNbO3 crystals. | · · | | |
| UNIT-3 | 3 | | 9L | | |
| Optical | Kerr eft | onlinear process: Third Harmonic Generation, Self focusing, Photo-thermal sfect, Self phase modulation, Four wave mixing concept and measurements, ss, Upconversion process, Z-scan technique. | 1 1. | | |
| UNIT- | UNIT-4 9L | | | | |
| wave co | Raman Spectroscopy: Raman Spectroscopy, Stimulated Raman scattering (SRS), Quantum theory, Coupled wave concept of SRS, Inverse Raman Effect, Coherent anti-stokes Raman Spectroscopy, Hyper-Raman effect, Stimulated Raman Gain and Loss Spectroscopy. | | | | |
| | ice Book | | | | |
| | Laser Fundamentals, William T. Silfvast, Cambridge University Press, 2003. Industrial Applications of Lasers, John F. Ready, Academic Press, 2012. | | | | |

| Course | Course Outcomes: Students will be able to: | | |
|--------|---|--|--|
| CO1 | learn laser technology and its advancement for defence. | | |
| CO2 | Design and develop lab scale lasers and 3D objects. | | |
| CO3 | Develop various laser detection techniques and perform experiments. | | |

| Course PHPE | | Materials Science | Credits 3-0-0: 3 | | |
|------------------------------------|--|--|--------------------------------|--|--|
| Course | Educat | ional Objectives : | | | |
| CEO1 | CEO1 To impart knowledge in the field of material and their applications in engineering. | | | | |
| CEO2 | To und | erstand the origin of mechanical and thermal properties of materials. | | | |
| CEO3 | To prepare the students to take up the future challenges related to advanced materials for developing futuristic devices. | | | | |
| UNIT-1 | L | | 7 L | | |
| relations Crystalli environr | ship in the international sector of the sect | listorical perspective of Materials Science, Classification of materials, Struct material, multiphase materials, Advance materials- polymers, ceramics and its effect on physical properties, metal, ceramic, polymers, Future materials, plications of materials. | l composites, Materials and | | |
| UNIT-2 | | | 7 L | | |
| Concept | of diff | lids: Introduction, Mechanisms of diffusion, Types of diffusion, Fick's law erent types of diffusion coefficients, Factors affecting diffusion coefficient iffusion coefficient, The Kirkendall effect, Darken analysis, Applications of diffusion | , Temperature | | |
| UNIT-3 | | | 7 L | | |
| strength, and frac | , modulu cture; T | perties: Introduction, elastic deformation- Stress-strain response of materials; y is of elasticity, toughness, Elastic Properties of Materials; plastic deformation ensile Properties, True Stress and Strain, Elastic recovery after plastic ear, and Torsional deformation, Hardness, Variability of material properties. | - fatigue, creep | | |
| UNIT-4 | 1 | | 7 L | | |
| thermal | Thermal Properties: Introduction, specific heat, thermal conductivity, Thermal expansion, thermal stress, thermal stability, Thermal radiation, emissivity, Relationship between structure and thermal properties of materials, Phase Transition, Experimental methods for thermal analysis of materials, Thermoelectric properties. | | | | |
| Referen | ce Book | s: | | | |
| 2. N 3. I | \mathcal{E} | | | | |

| Course | Course Outcomes: Students will be able to: | | |
|--------|---|--|--|
| CO1 | Understand different types of materials for various applications. | | |
| CO2 | Understand thermal properties of materials. | | |
| CO3 | Develop futuristic devices. | | |

Open Elective – I (Semester-III):

| S.No. | Course Code | Course Title |
|-------|--------------------|--|
| 1. | PHOE581 | Energy Materials and Devices |
| 2. | PHOE583 | Polymers, Ceramics and Composite Materials |
| 3. | PHOE585 | Semiconductor Devices |

Open Elective – II (Semester-IV):

| S.No. | Course Code | Course Title |
|-------|--------------------|--|
| 1. | PHOE582 | Fiber Optics and Optical Communication Systems |
| 2. | PHOE584 | Biomedical Instrumentation |
| 3. | PHOE### | NPTEL/SWAYAM/edX |

Open Elective NPTEL/SWAYAM/edX Courses:

| S.No. | Course Code | Course Title |
|-------|--------------------|---|
| 1. | PHOE### | Fundamentals of Artificial Intelligence |
| 2. | PHOE### | Cyber Security and privacy |
| 3. | PHOE### | Educational Leadership |
| 4. | PHOE### | Artificial Intelligence: Search methods for |
| | | problem solving |
| 5. | PHOE### | Entrepreneurship |
| 6. | PHOE### | Machine Learning and Deep Learning— |
| | | Fundamentals and Applications |
| 7. | PHOE### | Learning Analytics Tools |

| Course PHOE | | Energy materials and devices | Credits 3-0-0: 3 | |
|----------------|--|---|------------------|--|
| | | onal Objectives : | 500.5 | |
| CEO1 | | e graduates understand the use of nanomaterials in energy generation and storage. | | |
| CEO2 | | bit understanding of the sources of energy and the methods of energy conversion is | n | |
| | | chnology. | | |
| CEO3 | To gain | the knowledge solar energy, electrochemical storage of energy and fuel cells. | | |
| UNIT-1 | L. | | 7 L | |
| Introdu | ction: E | nergy challenges, Energy consummation, Current sources of energy, Status of energy | ergy map, | |
| Energy p | policies, | Conservation of energy, Alternative energy sources, Development and impleme | ntation of | |
| renewab | le energ | y technologies, role of renewable energy sources, Energy transport, conversion an | d storage, | |
| Sustaina | | gy. | | |
| UNIT-2 | | | 7 L | |
| | 0. | undamentals of solar cells, Types of solar cells, Photovoltaic effect, Semiconductin | 0 | |
| 01 | | Band gap engineering, Solar cell properties and design, p-n junction, Photodiode | | |
| | - | orts, charge carrier generation, recombination, I-V characteristics, Tandem struct | - | |
| | and trip | le-junction, solar panels, thin film solar cells, solar cell applications, solar cell mar | ufacturing | |
| process. | | | | |
| UNIT-3 | | | 7 L | |
| | | I Energy Storage Devices: Thermodynamics of electrochemical reaction Li- ion | | |
| | | materials for Li-ion batteries, Principle of supercapacitor, Advanced sup | - | |
| | | sics of Fuel cells - working principle of fuel cells and related thermodynamics | | |
| | electrochemistry, Fuel cell types ; SOFC, MCFC, PAFC, PEFC, Water management in PEFCs-Current issues | | | |
| in PEFC | | | 7 T | |
| UNIT-4 | | יות ני, י, וית ני, וית 1, י | 7 L | |
| | | and Piezoelectric Energy: Thermoelectric and Pizoelectric materials, Fabri | | |
| | | of thermoelectric devices, Bulk thermoelectric materials performance, The | | |
| | | electric harvester design, Micro and nanoscale energy harvesting, Fabric | ation and | |
| | | of piezoelectric devices, Strategies for optimizing efficiency, Future directions. | | |
| Referen | | s: ustainable world by L. Freris, D. Infield, Wiley, 2008. | | |
| - | • | • • • • | | |
| | | s for Sustainable Energy by Quan (Ed.), Springer, 2016. | | |
| | 3. Nanomaterials in Energy Devices by Jun HiengKait CRC Press, 2017. | | | |
| 4. Adva | nced nan | omaterials and their applications in renewable energy by J. Louise , L. S. Bashir , 2015. | | |
| | | | | |

| Course Outcomes: Students will be able to: | | |
|--|---|--|
| CO1 | Technically skilled to comprehend the principles behind energy storage mechanism. | |
| CO2 | To gain a broad understanding of concepts and applications of batteries and super capacitors. | |
| CO3 | Design and fabricate solar cells, electrochemical storage devices and fuel cells. | |

| | | Credits 3-0-0: 3 | |
|----------------------------------|-------------------------------------|--|-------------------------------------|
| Course | Educati | onal Objectives : | |
| CEO1 | To imp | art fundamental knowledge about polymer, ceramic and composite materials. | |
| CEO2 | | erstand processing techniques of polymer and ceramics. | |
| CEO3 | 1 1 | pare the students to develop the advanced materials through composite material | |
| UNIT-2 | | | 7 L |
| Molecul transitio | ar weigl n, Thern | Chemical Bonding: Polymerization mechanism, Addition and Condensation p hts and their distribution, Simple and hindered rotation, Crystallinity and r nosetting and Thermoplastic Polymers, Conducting polymers and their types, D gated polymers, Solatron and polaron formation in conducting polymers. | nelting, Glass |
| UNIT- | 2 | | 7 L |
| Reinford Enhance | ements, ment, ca | Aterials: Introduction and overview, Types of Composite Materials, Composite Materials, Factors affecting mechanical and electronic properties studies of composite materials for defense applications. | ties, Property |
| UNIT | | | 7 L |
| and Elec consolid matrix c | etrical co ation; Pi omposite | Polymers Matrix Composites: Bonding and crystal structure; Defects in Ceram nductivity of ceramic materials. Synthesis of ceramic powder and nanoparticles cocessing of ceramics and polymers matrix composites, Interfaces and propertie es, Thermal shock resistance, Biodegradable Polymer Composites, Applications | s and their as of ceramics s. |
| UNIT- | | | 7 L |
| | | Composites: Aluminium and Magnesium based Matrix Composites; Titanium rication and Applications. | based Matrix |
| Referen | ce Book | s: | |
| Wil | ey & So | ience, V.R. Gowariker, N.V. Viswanathan and JayadevSreedhar , Halstens, New York, 1986. f Polymerization, George Odian , John Wiley & Sons, 2004. | ed Press, John |
| | 1 | to Ceramics, W.D. Kingery, H.K. Bowen and D.R. Uhlmann, Wiley, 1960. | |
| | | ds of ceramics, W.M. Barsoum, CRC Press, 2002. | |
| | | Materials Science and Engineering, Krishnan K. Chawla, Springer, 2012. | |

| Course | Course Outcomes: Students will be able to: | | |
|--------|--|--|--|
| CO1 | Understand different types of materials for various applications. | | |
| CO2 | Understanding will improve regarding mechanical properties of materials. | | |
| CO3 | CO3 Understand the properties of new materials useful for developing futuristic devices. | | |

| | e Code E 585 | Semiconductor Devices | Credits 3-0-0: 3 |
|---|---|--|---|
| Course | Educati | onal Objectives : | |
| CEO1 | | lop the understanding of Physics essential for Electronics Engineering students. | |
| CEO2 | | knowledge of electronic and semiconducting properties of materials. | |
| CEO3 | | erstand theories relevant to the engineering principles of Semiconductor devices. | |
| UNIT-1 | | | 4 L |
| Review | of Band | theory of solids: Metal, Insulator, and Semiconductors; Periodic structures, Ori | gin of Energy |
| | | eorem, Kronig-Penney Model (qualitative), E-K diagram, Brillouin Zones-exter | |
| | | e schemes, Concept of Fermi energy Electrons and Holes, Concept of effective n | |
| | | rect and Indirect Band gap semiconductors. Effect of temperature and electric fiel | |
| structur | e. | | |
| UNIT-2 | 2 | | 10 L |
| Diffusion Reed th Electric for the | on current eory of re al conduct measurent ion spection | and acceptors, Equilibrium and extrinsic carrier concentration, Carrier transport, Mobility, Einstein relation, Excess carrier generation and recombination, H ecombination, Equilibrium and non-equilibrium processes, Charge transport equicitivity and mobility of charge carriers, mechanisms of scattering; Four probe an nent of conductivity, carrier concentration and mobility; Measurement of ban roscopy and Effective mass- Cyclotron resonance experiment. | all-Shockley- ation; nd Hall effect |
| Junctio | ons and | Devices: Types of junctions, Ohmic and Schottky contacts, Schottky barrie | and barrier |
| lowerin | g effects, | Theory of p-n junction, the concept of depletion later, resistance and capacitar | nce across the |
| depletio | on layer (| Charge transport in a p-n junction; Practical junctions and Ideality factor; Space | ce charge and |
| | - | ances. Impurity profiling through capacitance measurements. | |
| • - | - | yer and multilayer devices and their characteristics: PN diode; Light Emitting D | viodes; Solar |
| | | tors; Tunnel diode, Transistors; Field Effect Transistors. | |
| UNIT-4 | | | 8 L |
| | | ols and Techniques: Importance of Vacuum in fabrication- methods of achieved achieve | - |
| - | - | techniques, Wafer cleaning techniques, Surface conditioning and modificatio | - |
| | | olithography, Doping techniques (Diffusion and Ion implantation), Metallizati | on (Physical |
| | | n), semiconductor device sealing and packaging. | |
| | ice Book | s: niconductor Devices: Physics and Technology, John Wiley publication, 2013. | |
| | | amen, Semiconductor Physics and Devices: Basic Principles, McGraw-Hill publication | 2012 |
| | | man, Solid State Electronic Devices, Prentice-Hall of India, 2012. | , 2012. |
| | | h, Semiconductor Devices-Basic Principles, John Wiley publication, 2008. | |
| - | - | I, Introduction to Solid State Physics, John Wiley publication, 2013. | |
| | | | |
| Course | Outcom | es: Students will be able to: | |
| CO1 | Solve an | nd realize Electronics Engineering problems and challenges. | |

| CO1 | Solve and realize Electronics Engineering problems and challenges. |
|-----|---|
| | Understand fundamentals of semiconducting properties of materials for technological applications. |
| CO3 | Realize the operation mechanism of various electrical and electronic devices. |

| PHPH | e Code High Energy Physics E 552 | Credits 3-0-0: 3 |
|--|---|--|
| Course | Educational Objectives : | |
| CEO1 | To familiarize the students about fundamental entities of the up how the universe is made off! | niverse and their interactions and |
| CEO2 | To develop understanding of perturbation theory and Feynman scattering measurements. | Rules to apply in high energy |
| CEO3 | To develop understanding of Standard model of particle Physic | |
| UNIT-1 | | 8 L |
| Gravitat | tary Particles: Introduction to Four Fundamental Forces tional force, Strong force and Week forces; Fundamental entities prs; Basics of Quantum Chromodynamics, Strong coupling and A | -quarks, leptons, mediators, Quarks |
| UNIT- | 2 | 10 L |
| Isospin f Mesons | tries and Quarks: Symmetries, Conservation laws and Groups for particles and antiparticles, The Group SU(3)—Isospin and st and Baryons. Construction of wave function for bound states. Ma. Color factors. | rangeness, Quark structures of |
| UNIT-3 | 3 | 10L |
| Symmet | rd Model (SM) of Particle Physics: Local gauge transform try, Noether's theorem, spontaneous symmetry breaking, Hig d Model of Particle Physics. | |
| UNIT- | .4 | |
| | | 8 L |
| correction function | Ations in High Energy Scattering Experiments: Photon self-en- ons, Soft BremsstrahlungClassical Computation, Quantum con a in formal structure and evaluation through Feynman Parameter | ergy correction, Radiative nputation. The electron vertex |
| correction function Referen | ons, Soft BremsstrahlungClassical Computation, Quantum con in formal structure and evaluation through Feynman Parameter ice Books: | ergy correction, Radiative nputation. The electron vertex ization. |
| correction function Referen 1. Quar John | ons, Soft BremsstrahlungClassical Computation, Quantum com a in formal structure and evaluation through Feynman Parameter ice Books: rks and Leptons: An Introductory Course in Modern Particle Phy a Wiley & Sons, 1993. | ergy correction, Radiative nputation. The electron vertex ization. ysics, F. Halzen and A. Martin , |
| correction function Referen 1. Quar John 2. Intro | ons, Soft BremsstrahlungClassical Computation, Quantum com in formal structure and evaluation through Feynman Parameter ice Books: rks and Leptons: An Introductory Course in Modern Particle Phy in Wiley & Sons, 1993. oduction to elementary Particles, D. J. Griffiths , John Wiley & S | ergy correction, Radiative nputation. The electron vertex ization. ysics, F. Halzen and A. Martin , Sons, 2006. |
| correction function Referen 1. Quar John 2. Intro 3. The s | ons, Soft BremsstrahlungClassical Computation, Quantum com in formal structure and evaluation through Feynman Parameter ice Books: rks and Leptons: An Introductory Course in Modern Particle Phy in Wiley & Sons, 1993. Induction to elementary Particles, D. J. Griffiths , John Wiley & S strange Theory of Light and Matter, Richard P. Feynman , Prin | ergy correction, Radiative nputation. The electron vertex ization. ysics, F. Halzen and A. Martin , Sons, 2006. ston University Press, 1983. |
| correction function Referen 1. Quar John 2. Intro 3. The s 4. Quar | ons, Soft BremsstrahlungClassical Computation, Quantum com in formal structure and evaluation through Feynman Parameter ice Books: rks and Leptons: An Introductory Course in Modern Particle Phy in Wiley & Sons, 1993. oduction to elementary Particles, D. J. Griffiths , John Wiley & S strange Theory of Light and Matter, Richard P. Feynman , Prin ntum Electrodynamics, W. Greiner, J. Reinhar t, Springer, 2002 | ergy correction, Radiative nputation. The electron vertex ization. ysics, F. Halzen and A. Martin , Sons, 2006. ston University Press, 1983. 3. |
| correction function Referen 1. Quar John 2. Intro 3. The 4. Quar 5. Phote | ons, Soft BremsstrahlungClassical Computation, Quantum com in formal structure and evaluation through Feynman Parameter ice Books: rks and Leptons: An Introductory Course in Modern Particle Phy in Wiley & Sons, 1993. Induction to elementary Particles, D. J. Griffiths , John Wiley & S strange Theory of Light and Matter, Richard P. Feynman , Prin | ergy correction, Radiative nputation. The electron vertex ization. ysics, F. Halzen and A. Martin , Sons, 2006. ston University Press, 1983. 3. |

| Course | Course Outcomes: Students will be able to: | | |
|--------|---|--|--|
| CO1 | CO1 Illustrate the fundamental constituent of the universe. | | |
| CO2 | Apply Feynman rules technique to the high energy scattering process measured in experiments like LHC, COMPASS, HERA, LEP etc. | | |
| CO3 | Cultivate critical thinking on symmetries and conservation laws involved in cutting edge research. | | |

| Course Code Ph PHPE 554 | | Photonics | Credits 3-0-0: 3 | |
|----------------------------|--|--|------------------|--|
| | Course Educational Objectives : | | | |
| CEO1 | | art the fundamental knowledge about the light matter interaction. | | |
| CEO2 | To give | e the proper understanding of novel developments in the area of photonics. | | |
| CEO3 | To prov | vide understanding of the principles of photon generation, propagation and mani | pulation. | |
| UNIT-1 | | | 9 L | |
| Mean ph light; Pro | oton flu opagatio | ual nature of light, Photon energy, Photon position, Photon, momentum, Photon x, Photon number statistics, Quantum states of light: Coherent-state light and S n of EM waves in anisotropic materials, Uniaxial and biaxial materials. | | |
| UNIT-2 | | | 9 L | |
| dispersio dispersio | on and a | sses and Dispersion: Linear and nonlinear losses, Signal degradation in optical ttenuation; Pulse dispersion in graded index optical fibers, Material dispersion esign considerations. | n, Waveguide | |
| UNIT-3 | | | 9 L | |
| | • | al: Basic Concepts, Photonic Bandgap Structures, Features of Photonic Cryst hotonic crystal Sensors, Method of Fabrication. | als, Photonic | |
| UNIT- | 4 | | 9 L | |
| techniqu | Fabrication of photonic structures: Fabrication techniques of photonic structures: Fabrication steps, Coating techniques, etching processes: wet and dry; types of masks, Basic idea of photolithography and electron beam lithography, Applications of photonic devices. | | | |
| Referen | Reference Books: | | | |
| 2. F 3. N | Photonics by Ralf Menzel: Springer Verilog 2001. Nonlinear Optics by Boyd: Academic Press 2010. | | | |

| Course Outcomes: At the end of the course students will be able to: | | |
|---|--|--|
| CO1 | Understand the concept of the photons, their generation and manipulation. | |
| CO2 | Apply the relevant concepts of the photonics for the development of novel photonic technologies. | |
| CO3 | Solve technical and strategic problems related to the light-matter interaction. | |

| PHPE 556 3-0-0: 3 Course Educational Objectives : 3-0-0: 3 CEO1 Student will gain fundamental knowledge of thin film growth processes and techniques. CEO2 Student will be able to understand basic physics behind various thin film growth techniques. CEO3 Student will be able to understand basic physics behind various thin film growth techniques. CEO3 Student will be able to understand basic physics of solidification, cooling curve, Thermodynamics and kinetics of Nucleation and growth mechanisms, Critical radius of nuclei, Grain formation, Defects in thin films, Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. 81 Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. 10 L UNIT-3 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron spectroscopy (AES). 8 L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting optical coating, Photo-thermal Coatings, Optical Filters, single layer and multilayer Organic Light Emitting Diodes (PLEDs), single layer an | ~ | <u>a</u> 1 | | | | |
|--|---|------------|--|------------------|--|--|
| Course Educational Objectives : CEO1 Student will gain fundamental knowledge of thin film growth processes and techniques. CEO2 Student will be able to understand basic physics behind various thin film growth techniques. CEO3 Student will learn the hybrid thin film growth approaches and design thin film based devices. UNIT-1 8 L Introduction: Technological status, Physics of solidification, cooling curve, Thermodynamics and kinetics of Nucleation and growth mechanisms, Critical radius of nuclei, Grain formation, Defects in thin films, Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. UNIT-2 8 L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. UNIT-3 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X-Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). UNIT-4 8 L Thin Film Properties And Ap | | | Thin Film Physics And Applications | Credits | | |
| CEO1 Student will gain fundamental knowledge of thin film growth processes and techniques. CEO2 Student will be able to understand basic physics behind various thin film growth techniques. CEO3 Student will learn the hybrid thin film growth approaches and design thin film based devices. UNIT-I CANCOLOGICAL STATES AND ADDED TO THE CONTROL STATES AND ADDED TO THE STATE | | | l Objectives • | 5-0-0.5 | | |
| CEQ2 Student will be able to understand basic physics behind various thin film growth techniques. CEO3 Student will learn the hybrid thin film growth approaches and design thin film based devices. UNIT-1 8 L Introduction: Technological status, Physics of solidification, cooling curve, Thermodynamics and kinetics of Nucleation and growth mechanisms, Critical radius of nuclei, Grain formation, Defects in thin films, Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. 8 L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques. Doctor blade technique, Film patterning techniques: wet and dry etching. 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X-Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). 8 L Thin Film Properties And Applications: Multilayer Optical Films, Single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. <t< td=""><td></td><td colspan="5"></td></t<> | | | | | | |
| CEQ3 Student will learn the hybrid thin film growth approaches and design thin film based devices. UNIT-1 8 L Introduction: Technological status, Physics of solidification, cooling curve, Thermodynamics and kinetics of Nucleation and growth mechanisms, Critical radius of nuclei, Grain formation, Defects in thin films, Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. 8 L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. 10 L Characterization Techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X-Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). 8 L Thin Film Properties And Applications: Multilayer Optical Films, single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. 8 L Physical vapour deposition of thin films, John E. Mahan, John Wiley & Sons, 2000. 4. Materials science of thin films: Deposition and structure, Milton Ohring, Elsevier, Inc., 2002. | | | | | | |
| 8 L Introduction: Technological status, Physics of solidification, cooling curve, Thermodynamics and kinetics of Nucleation and growth mechanisms, Critical radius of nuclei, Grain formation, Defects in thin films, Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. UNIT-2 8 L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. 10 L UNIT-3 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X-Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). UNIT-4 UNIT-4 8 L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting Diodes (OLEDs), single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. <td col<="" td=""><td>0202</td><td></td><td></td><th></th></td> | <td>0202</td> <td></td> <td></td> <th></th> | 0202 | | | | |
| Introduction: Technological status, Physics of solidification, cooling curve, Thermodynamics and kinetics of Nucleation and growth mechanisms, Critical radius of nuclei, Grain formation, Defects in thin films, Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. UNIT-2 8L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. UNIT-3 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X-Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). UNIT-4 8 L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. Reference Books: 1. Solid State Electronic Devices, Ben G. Streetman, Prentice-Hall of India, 2012. 2. Semiconductor Devices-Basic Principles, Jaspreet Singh, John Wiley publication, 2008. 3. Physical vapour deposition of thin films; John E. Mahan, John Wiley Sons, 2000. 4. Materials science of thin films: Deposition and structure, Milton Ohring, Elsevier, Inc., 2002. | | | | 8 L | | |
| Nucleation and growth mechanisms, Critical radius of nuclei, Grain formation, Defects in thin films, Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. UNIT-2 8L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. UNIT-3 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X- Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). UNIT-4 8 L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting optical coating, Photo-thermal Coatings, Optical Filters, single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. Reference Books: 1. Solid State Electronic Devices, Ben G. Streetman , Prentice-Hall of India, 2012. 2. Semiconductor Devices-Basic Principles, Jaspreet Singh , John Wiley publication, 2008. 3. Physical vapour deposition of thin films; John E. Mahan , John Wiley & Sons, 2000. 4. Materials science of thin films: Deposition and structure, Milton Ohring , Elsevier, Inc., 2002. | | tion: T | echnological status, Physics of solidification, cooling curve, Thermodynamics an | | | |
| Adsorption and desorption, Surface conditioning and modification methods: Cleaning methods, Thermal annealing, Surface Ozonisation, Plasma processing. UNIT-2 8 L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X-Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). 8 L UNIT-4 8 L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting optical coating, Photo-thermal Coatings, Optical Filters, single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin bilm transistors, Thin bilm transistors, Pentice-Hall of India, 2012. 2. Semiconductor Devices-Basic Principles, Jaspreet Singh, John Wiley publication, 2008. 3. Physical vapour deposition of thin films, John E. Mahan, John Wiley & Sons, 2000. 4. Materials science of thin films: Deposition and structure, Milton Ohring, Elsevier, Inc., 2002. | | | | | | |
| UNIT-2 8 L Fabrication Techniques: Film thickness uniformity and purity, Evaporation hardware and techniques, Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. UNIT-3 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X- Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). 8 L UNIT-4 8 L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting optical coating, Photo-thermal Coatings, Optical Filters, single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. Reference Books: 1. Solid State Electronic Devices, Ben G. Streetman, Prentice-Hall of India, 2012. 2. Semiconductor Devices-Basic Principles, Jaspreet Singh, John Wiley publication, 2008. 3. Physical vapour deposition of thin films, John E. Mahan, John Wiley & Sons, 2000. 4. Materials science of thin films: Deposition and structure, Milton Ohring, Elsevier, Inc., 2002. | | | | | | |
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| Resistance heating and electron beam evaporation, Fundamentals of Chemical Vapor Deposition, Sputtering, Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. UNIT-3 10 L Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X- Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). 8 L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting optical coating, Photo-thermal Coatings, Optical Filters, single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. Reference Books: 1. Solid State Electronic Devices, Ben G. Streetman , Prentice-Hall of India, 2012. 2. Semiconductor Devices-Basic Principles, Jaspreet Singh , John Wiley publication, 2008. 3. Physical vapour deposition of thin films, John E. Mahan , John Wiley & Sons, 2000. 4. Materials science of thin films: Deposition and structure, Milton Ohring , Elsevier, Inc., 2002. | UNIT-2 | | | 8 L | | |
| Pulsed laser deposition, Langmuir Blodgett technique, Spin and Dip coating techniques, Doctor blade technique, Film patterning techniques: wet and dry etching. Iot UNIT-3 Iot Characterization Techniques: Film Thickness measurement- Optical techniques: Interferometry and Ellipsometry, Mechanical techniques: Stylus Profilometry, Structural studies: Energy Dispersive Studies by X-Rays, Surface studies: Surface topography and thin film morphological studies by SEM and AFM, Film composition and depth profiling techniques: Photoelectron spectroscopy- XPS, UPS, Auger Electron Spectroscopy (AES). UNIT-4 B L Thin Film Properties And Applications: Multilayer Optical Film Applications: reflecting and anti-reflecting optical coating, Photo-thermal Coatings, Optical Filters, single layer and multilayer Organic Light Emitting Diodes (OLEDs), single layer and multilayer Polymeric Light Emitting Diodes (PLEDs), Thin film solar cells, Thin Film Transistors, Thin film battery. Reference Books: 1. Solid State Electronic Devices, Ben G. Streetman, Prentice-Hall of India, 2012. 2. Semiconductor Devices-Basic Principles, Jaspreet Singh, John Wiley publication, 2008. 3. Physical vapour deposition of thin films, John E. Mahan, John Wiley & Sons, 2000. 4. Materials science of thin films: Deposition and structure, Milton Ohring, Elsevier, Inc., 2002. | Fabricat | ion Te | chniques: Film thickness uniformity and purity, Evaporation hardware and | l techniques, | | |
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| 4. Materials science of thin films: Deposition and structure, Milton Ohring, Elsevier, Inc., 2002. | | | | | | |
| • | | • | | 2002. | | |
| $\mathbf{J}_{\mathbf{i}} = \mathbf{I}_{\mathbf{i}} + $ | | | Phenomena, K. L. Chopra , McGraw-Hill, New York, 1969. | | | |

| Course Outcomes: Students will be able to: | | |
|--|---|--|
| CO1 | Have knowledge of the physics of various thin film growth approaches. | |
| CO2 | Analyze practical problems on various thin film growth techniques. | |
| CO3 | Design thin film based devices. | |

| Course Code PHPE 558 | | Nuclear Technology | Credits 3-0-0: 3 |
|--|--|---|----------------------|
| Course | Educati | onal Objectives : | |
| CEO1 | To give | understanding of different types of radiations and their interaction of with | matter. |
| CEO2 | To gain | knowledge about design and working of gas filled and semiconductor radi | ation detectors. |
| CEO3 | | | |
| UNIT | -1 | | 6 L |
| Electron Nuclear | magnetic Radiatio | Auclear Radiations : Interaction of Radiations with Matter: Charge Particles Radiations (Photoelectric effect, Compton scattering, Pair production) and on Detectors, Various Types of Radiation Detectors: Gas ionization based de rtional counters, G.M. detectors, & their design considerations. | Neutrons. |
| UNIT- | 2 | | 10 L |
| flight sp Semicor Resolut | bectrosco nductor ion and a | ctors: Split Anode detector, Multi-wire detectors, Particle by Particle iden py, Bubble chamber, Cloud chamber, Scintilation detector. radiation detectors: Mechanism of Electron-Hole Pair generation, Far recombination, Characteristics of Homogeneous and Junction type detector tions, Signal Generation and Frequency Response. | no Factor, Energy |
| UNIT- | 3 | | 8 L |
| Nuclear | fission, reactor, | rs: Nuclear reaction and their type, Conservation laws, Direct and compoun fission products, Mass and energy distribution of fission products, nuclear fi Nuclear Fuel, Control rods, nuclear fusion–controlled thermonuclear reaction | ssion reactors, Fast |
| | | d Instrumentation Circuits: Photomultiplier tube, Noise Conside | |
| Preamplifiers- Voltage, Current and Charge sensitive preamplifiers, Signal Transport and design considerations of signal cables, Fast pulse amplifiers, Pulse Shaping circuits- Delay Line, CR-RC Semi-Gaussian and semi- triangular, Filtering circuit, discriminator module, Pulse height analyzers- Single and multi-channel Analyzers, Analog to Digital Conversion, Various Electronics Noises, Noise in Amplifiers and ADCs. | | | |
| Referen | ice Book | s: | |
| 2. 3. | Nuclear In Solid Stat Springer, | | e& R. M. Walker, |
| 4. ' | 4. Techniques for nuclear and particle physics experiments: W. R. Leo, Springer, 1948. | | |

| Course | Course Outcomes: Students will be able to: | | |
|--------|---|--|--|
| CO1 | Understand different types of radiations and their interaction of with matter. | | |
| CO2 | Understand design and working of gas filled and semiconductor radiation detectors with associated | | |
| | electronics. | | |
| CO3 | Understand solid state nuclear track detectors and their application for measurement of | | |
| | environmental radioactivity. | | |

| Course PHPE | J | Credits 3-0-0: 3 | |
|---------------------------------|---|---------------------|--|
| Course Educational Objectives : | | | |
| CEO1 | To develop the understanding of physical process for designing Optoelectronic Instruments. | | |
| CEO2 | To understand the optoelectronic mechanisms in various optical detectors working in different | | |
| | range. | | |
| CEO3 | To utilize the optical sources and devices for research and industrial application. | | |

Optical Sources And Detectors: Sources and Detectors for IR, Visible, UV radiations, Constant illumination sources, Optical Fiber Sensors: Active and passive optical fiber sensor, intensity modulated, displacement type sensors.

UNIT-2

LASERS: Characteristics of laser radiation, Einstein Coefficients and Laser Amplification, Q-switching, Mode-locking, Types of lasers (solid state lasers, Gas lasers, Molecular Laser, Dye lasers) Diode laser array, Applications of Lasers.

UNIT-3

Optoelectronic Process And Spectrophotometers: Optoelectronics process and systems, Photoconductive devices, LDR; Photoemissive devices, Photomultiplier tube; Photovoltaic Devices, Tandem solar cell, and DSSC Solar cell; Photoinduced voltage; Solar Concentrators, Quantum dot solar cells, Construction of solar cell; factors affecting the solar cell; Monochromators: Prism, Grating and Filter; Dual beam Spectrophotometers.

UNIT-4

Optoelectronic Devices: Laser range finder, Laser Interferometers, Colorimeters, Flame-Photometers, Turbidity meters, LED: Mechanism, Design and Fabrication; Laser Diodes, Charge Couple Detector, Opto-isolator.

Reference Books:

- 1. Optoelectronics: An introduction, John Wilson, J. F. B. Hawkes, Prentice Hall Europe, 1998
- 2. Photoelectronic Devices by J. B. Danoe, 1991
- 3. Lasers and optical engineering by **P. Das,** Springer, 2011.
- 4. Lasers by Ghatak & Thyagrajan, Laxmi Publication, 2019.

Course Outcomes: Students will be able to:

CO1 Design optoelectronic Instruments.

CO2 Imply the mechanisms of various optical detectors.

CO3 Utilise optical sources and devices for research and industries.

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| Course Code PHOE 582 | | Fiber Optics and Optical Communication Systems | Credits 3-0-0: 3 |
|--|---|---|-------------------|
| Course | Educat | ional Objectives : | |
| CEO1 | To provide essential knowledge about fiber optic technology. | | |
| CEO2 | To convey the idea of the principles of light guidance inside the optical fibers. | | |
| CEO3 | To provide understanding of various potential applications of the optical fibers in optical communication systems and other fields. | | |
| UNIT | `-1 | | 9 L |
| Ray ana | alysis of | Basic elements of the fiber optic communication system; Single and multimoptical fiber: Propagation mechanism of rays in an optical fiber; Meridiona aperture; Electromagnetic mode theory for optical propagation. | - |
| UNIT | -2 | | 9 L |
| | ides: ste | echanics: Electromagnetic mode theory for optical propagation. Mode the p index optical fibers; Propagation characteristics of step index optical fibers | • |
| UNIT | -3 | | 9 L |
| dispersi | ion and a | Osses and Dispersion: Linear and nonlinear losses, Signal degradation in op attenuation; Pulse dispersion in graded index optical fibers, Material dispe esign considerations. | |
| UNIT | -4 | | 9 L |
| amplifie | ers: EDF | Applications, and Sustainability: Conventional applications of optical file A, Gain spectrum and gain band width, EDFAs for WDM transmission, he optical fibers other than the telecommunication industry. | - |
| Referen | nce Bool | KS: | |
| F. J. J. T. | C. Allar Gowar, ' Tamir, ' | ber optic communication" McGraw Hill, 2009. d, "Fiber Optics Handbook for engineers and scientists", McGraw Hill, 200 'Optical communication system", Prentice Hall, 1993. 'Integrated optics", Academic Press, 2010. & A. G. Chynoweth, "Optical Fibers Telecommunication", Academic Press | |
| Course | Outcon | nes: At the end of the course students will be able to: | |
| CO1 | | he concept of optical fiber technology, their applications, and the relevant izing and solving light guidance in different structures. | physics concepts |
| CO2 | Solve te | echnical and strategic problems related to the fabrication of optical fibers. | |
| CO3 | Realize industri | the various potential applications of the optical fibers in telecommunes. | ication and other |

Course Code PHOE 584

Course Educational Objectives :

| UNIT-1 | 10 L |
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| CEO3 | To apply the diagnostics and therapeutic tools in medical field. |
| CEO2 | To gain comprehensive knowledge of various processes related to human body and its organs. |
| CEO1 | To understand the utilization of different types of Biomedical Instruments for diagnostic purposes. |

Bio-Potentials and Electrodes: Introduction to the main biomedical instrumentation system and its components, problems encountered in the design of biomedical instrumentation system. Origin of Bioelectric potentials; The electrode-electrolyte system, Polarization, polarizable and non- polarizable electrodes, skin contact impedance, electrodes for ECG, EEG & EMG, microelectrodes, Biomedical Recorders: Electrocardiograph, electroencephalograph and electromyograph. Blood pressure measurement: Direct and indirect methods.

UNIT-2

Blood Flowmeters: Electromagnetic, Ultrasonic, NMR and Laser Doppler Blood flowmeters. Pulmonary Function Analysers: Respiratory volumes, wedge and ultrasonic spirometers, Fleischpneumo-tachometer. 8 L

UNIT-3

Biomedical Imaging Techniques: X-ray machine, Image intensifiers & image noise. Principles and theory of Tomographic Imaging, parallel and fan beam illumination, X-ray computed tomography, Emission computed tomography. Nuclear imaging techniques: PET, SPECT. Optical imaging and microscopy. Molecular and Cellular imaging, Contrast agents.

Nuclear Magnetic Resonance imaging and its application in the field of diagnostics, MRI, Benefits and limitations of MRI.

UNIT-4

Ultrasound Imaging and Therapy: Ultrasound, Ultrasonic scanning: A-scanners & B-scanners, Real time ultrasonic imaging systems, Therapy with ultrasonic waves, Biological effects of ultrasonic waves, Radiotherpy: Radiobiology and radiation physics treatment planning, radiation therapy, Particle beam therapy (hadrontherapy), biological effects of radiations, instrumentation for the medical use of radioisotopes, Dosimetry in modern radiation therapy, Dose measurement.

Reference Books:

- 1. A handbook of Biomedical Instrumentation, R S Khandpur, McGraw-Hill Education (India) Pvt Limited, 2003.
- Biomedical Instrumentation & Measurement, Leslie Cromwell, Fred J Weibell & ErichAPfeiffer. 2. Prentice-Hall, 1990.
- Medical Instrumentation: Application and Design. John G. Webster, John Wiley & Sons, 2009. 3.

Medicine & Clinical Engineering, Bertil Jacobson & John G Webster, Prentice- Hall. 1977. 4.

| Course Outcomes: At the end of the course students will be able to: | | |
|--|--|--|
| CO1 | Graduates will develop the understanding of utilization of different types of Biomedical | |
| | Instruments. | |
| CO2 | Graduates will have comprehensive knowledge of various processes related to human body and | |
| | its organs. | |
| CO3 | Graduates will be able to apply the diagnostics and therapeutic tools in medical field. | |

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